

# ANTREX Electronics

Electronic Components Sourcing Information

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## Product Reference Information

**Part Number:** ZX5T951GQTC  
**Manufacturer:** Diodes Incorporated  
**Package:** TO-261-4, TO-261AA  
**Availability:** Please confirm with sales

### Product Page:

<https://antrexco.com/product/details/diodes-incorporated/zx5t951gqtc.html>

### Request a Quote:

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## Contact Information

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### Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

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## Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

## Features

- $BV_{CEO} > -60V$
- $I_C = -5.5A$  High Continuous Collector Current
- $I_{CM} = -15A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < -70mV @ -1A$
- $R_{SAT} = 39m\Omega$  for a Low Equivalent On-Resistance
- $h_{FE}$  Specified Up to  $-10A$  for a High Gain Hold Up
- Complementary NPN Type: ZX5T851GQ
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **The ZX5T951GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

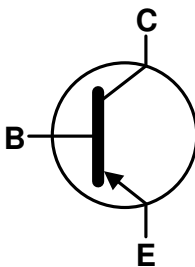
- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads.
- Solderable per MIL-STD-202, Method 208 
- Weight: 0.112 grams (Approximate)

## Applications

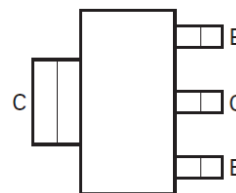
- DC-DC Converters
- MOSFET & IGBT Gate Drivers
- Charging Circuits
- Power Switches
- Motor Control



Top View



Device Symbol



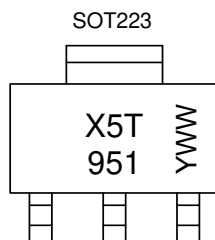
Top View  
Pin-Out

## Ordering Information (Note 4)

| Product     | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-------------|---------|--------------------|-----------------|-------------------|
| ZX5T951GQTC | X5T951  | 13                 | 12              | 4000              |

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



X5T 951 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 0= 2020)  
 WW or  $\bar{W}W$  = Week Code (01~53)

## Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic               | Symbol    | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage       | $V_{CBO}$ | -100  | V    |
| Collector-Emitter Voltage    | $V_{CEO}$ | -60   | V    |
| Emitter-Base Voltage         | $V_{EBO}$ | -7    | V    |
| Continuous Collector Current | $I_C$     | -5.5  | A    |
| Peak Pulse Current           | $I_{CM}$  | -15   | A    |

## Thermal Characteristics (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

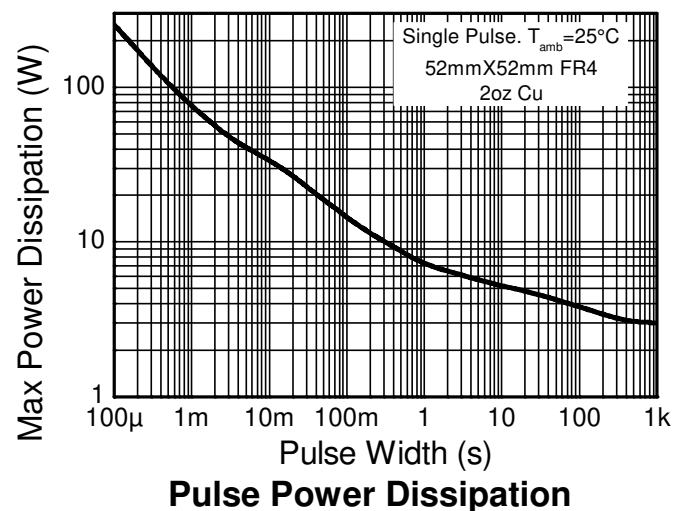
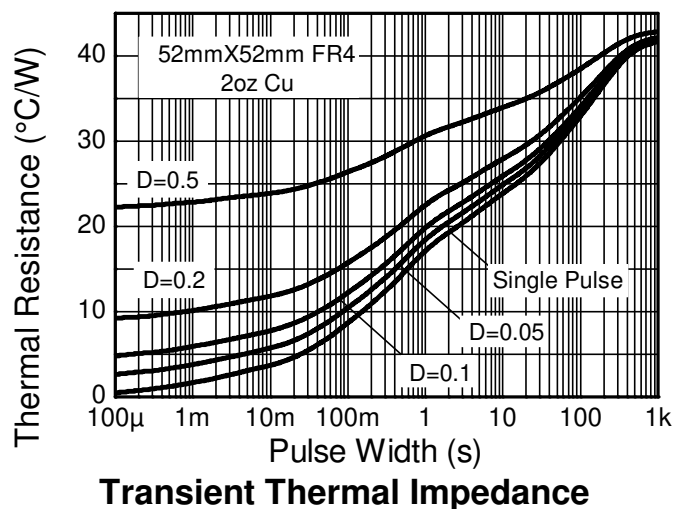
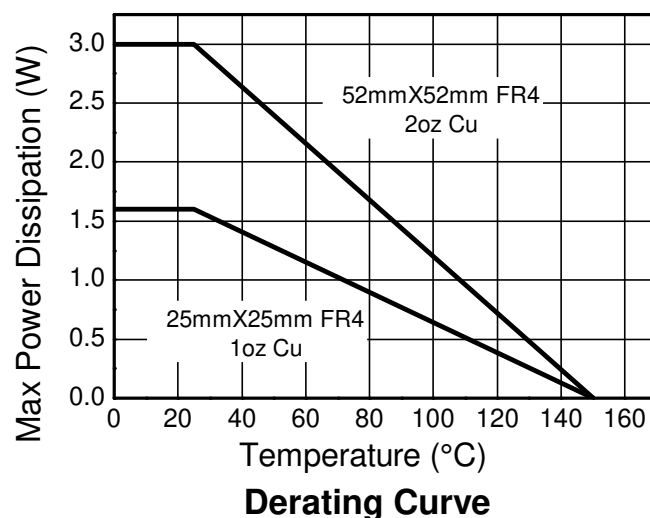
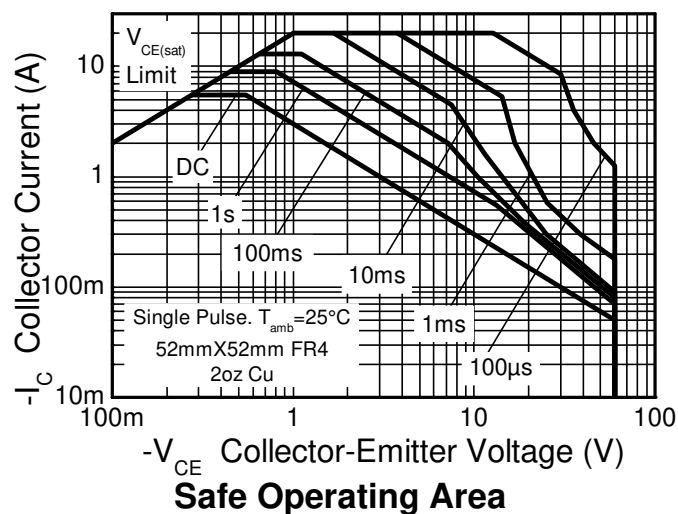
| Characteristic                          | Symbol          | Value       | Unit                       |
|-----------------------------------------|-----------------|-------------|----------------------------|
| Power Dissipation                       | $P_D$           | 3.0         | W                          |
| Linear Derating Factor                  |                 | 24          |                            |
|                                         |                 | 1.6         |                            |
|                                         |                 | 12.8        | $\text{mW}/^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 42          | $^\circ\text{C}/\text{W}$  |
|                                         | $R_{\theta JA}$ | 78          |                            |
| Thermal Resistance Junction to Lead     | $R_{\theta JL}$ | 10.48       |                            |
| Operating and Storage Temperature Range | $T_J, T_{STG}$  | -55 to +150 | $^\circ\text{C}$           |

## ESD Ratings (Note 8)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--------------------------------------------|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4000  | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | C           |

- Notes:
- For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  - Same as Note 5 except the device is surface mounted on 25mm x 25mm with 1oz copper.
  - Thermal resistance from junction to solder-point (at the end of the collector lead).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## Thermal Characteristics and Derating Information

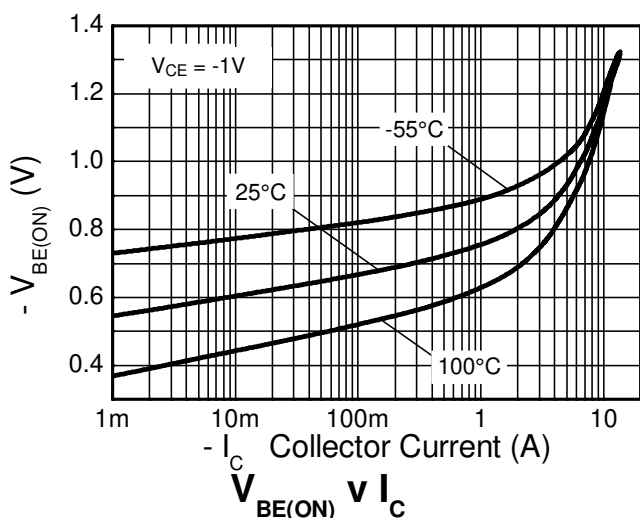
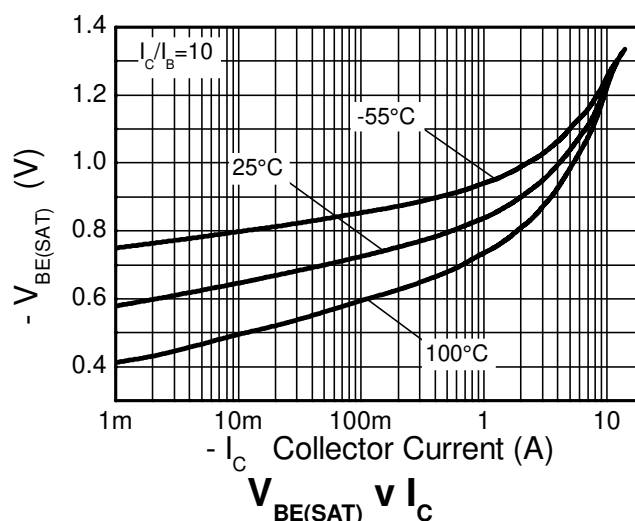
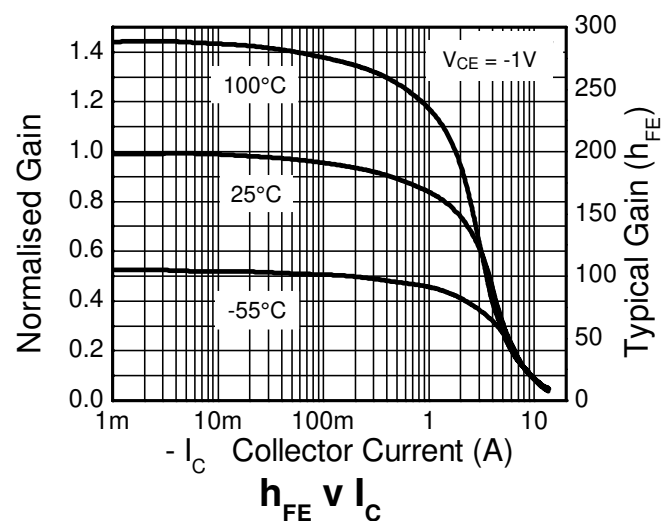
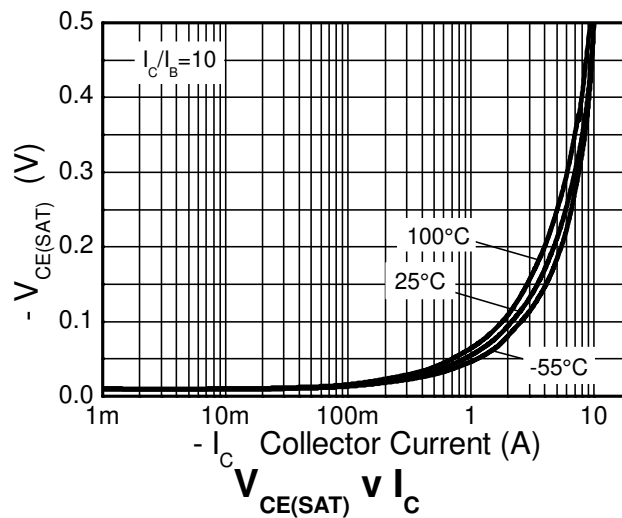
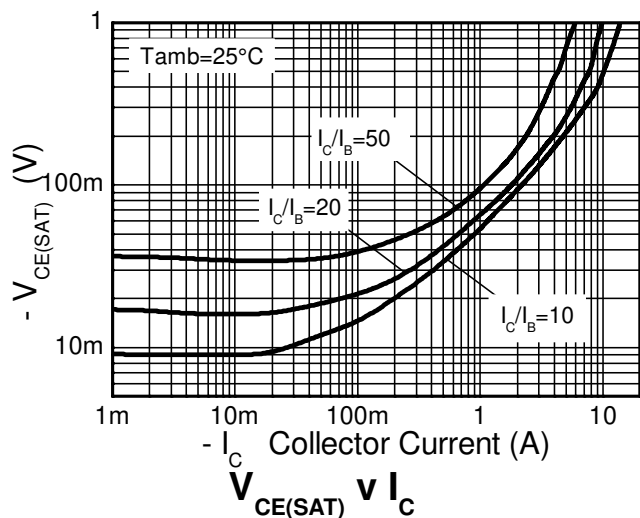


**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                                 | Symbol                                | Min  | Typ   | Max         | Unit                | Test Condition                                                                |
|------------------------------------------------|---------------------------------------|------|-------|-------------|---------------------|-------------------------------------------------------------------------------|
| Collector-Base Breakdown Voltage               | $BV_{CBO}$                            | -100 | -120  | —           | V                   | $I_C = -100\mu\text{A}$                                                       |
| Collector-Emitter Breakdown Voltage            | $BV_{CER}$                            | -100 | -120  | —           | V                   | $I_C = -1\mu\text{A}$ , $R_B \leq 1\text{k}\Omega$                            |
| Collector-Emitter Breakdown Voltage (Note 9)   | $BV_{CEO}$                            | -60  | -80   | —           | V                   | $I_C = -10\text{mA}$                                                          |
| Emitter-Base Breakdown Voltage                 | $BV_{EBO}$                            | -7   | -8.1  | —           | V                   | $I_E = -100\mu\text{A}$                                                       |
| Collector-Base Cutoff Current                  | $I_{CBO}$                             | —    | <-1   | -20<br>-0.5 | nA<br>$\mu\text{A}$ | $V_{CB} = -80\text{V}$<br>$V_{CB} = -80\text{V}$ , $T_A = +100^\circ\text{C}$ |
| Collector-Emitter Cutoff Current               | $I_{CER}$<br>$R \leq 1\text{k}\Omega$ | —    | <-1   | -20<br>-0.5 | nA<br>$\mu\text{A}$ | $V_{CB} = -80\text{V}$<br>$V_{CB} = -80\text{V}$ , $T_A = +100^\circ\text{C}$ |
| Emitter Cutoff Current                         | $I_{EBO}$                             | —    | <-1   | -10         | nA                  | $V_{EB} = -6\text{V}$                                                         |
| Static Forward Current Transfer Ratio (Note 9) | $h_{FE}$                              | 100  | 250   | —           | —                   | $I_C = -10\text{mA}$ , $V_{CE} = -1\text{V}$                                  |
|                                                |                                       | 100  | 200   | 300         |                     | $I_C = -2\text{A}$ , $V_{CE} = -1\text{V}$                                    |
|                                                |                                       | 45   | 90    | —           |                     | $I_C = -5\text{A}$ , $V_{CE} = -1\text{V}$                                    |
|                                                |                                       | 10   | 25    | —           |                     | $I_C = -10\text{A}$ , $V_{CE} = -1\text{V}$                                   |
| Collector-Emitter Saturation Voltage (Note 9)  | $V_{CE(sat)}$                         | —    | -15   | -25         | mV                  | $I_C = -100\text{mA}$ , $I_B = -10\text{mA}$                                  |
|                                                |                                       | —    | -55   | -70         |                     | $I_C = -1\text{A}$ , $I_B = -100\text{mA}$                                    |
|                                                |                                       | —    | -90   | -120        |                     | $I_C = -2\text{A}$ , $I_B = -200\text{mA}$                                    |
|                                                |                                       | —    | -195  | -250        |                     | $I_C = -5\text{A}$ , $I_B = -500\text{mA}$                                    |
| Base-Emitter Saturation Voltage (Note 9)       | $V_{BE(sat)}$                         | —    | -1030 | -1150       | mV                  | $I_C = -5\text{A}$ , $I_B = -500\text{mA}$                                    |
| Base-Emitter Turn-On Voltage (Note 9)          | $V_{BE(on)}$                          | —    | -920  | -1020       | mV                  | $I_C = -5\text{A}$ , $V_{CE} = -1\text{V}$                                    |
| Output Capacitance (Note 9)                    | $C_{obo}$                             | —    | 48    | —           | pF                  | $V_{CB} = -10\text{V}$ , $f = 1\text{MHz}$                                    |
| Transition Frequency                           | $f_T$                                 | —    | 120   | —           | MHz                 | $V_{CE} = -10\text{V}$ , $I_C = -100\text{mA}$<br>$f = 50\text{MHz}$          |
| Switching Time                                 | $t_{on}$                              | —    | 39    | —           | ns                  | $V_{CC} = -10\text{V}$ , $I_C = -1\text{A}$                                   |
|                                                | $t_{off}$                             | —    | 370   | —           |                     | $I_{B1} = -I_{B2} = -100\text{mA}$                                            |

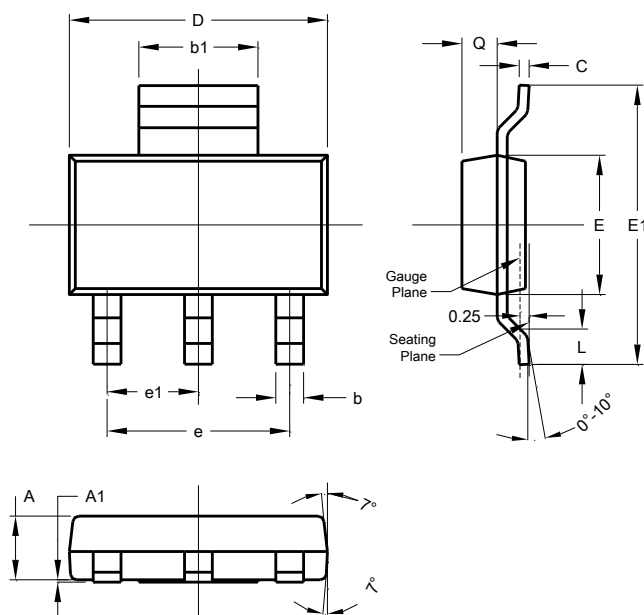
Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



## Package Outline Dimensions

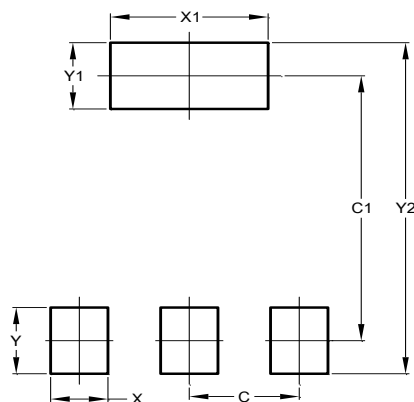
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



| SOT223               |       |      |      |
|----------------------|-------|------|------|
| Dim                  | Min   | Max  | Typ  |
| A                    | 1.55  | 1.65 | 1.60 |
| A1                   | 0.010 | 0.15 | 0.05 |
| b                    | 0.60  | 0.80 | 0.70 |
| b1                   | 2.90  | 3.10 | 3.00 |
| C                    | 0.20  | 0.30 | 0.25 |
| D                    | 6.45  | 6.55 | 6.50 |
| E                    | 3.45  | 3.55 | 3.50 |
| E1                   | 6.90  | 7.10 | 7.00 |
| e                    | -     | -    | 4.60 |
| e1                   | -     | -    | 2.30 |
| L                    | 0.85  | 1.05 | 0.95 |
| Q                    | 0.84  | 0.94 | 0.89 |
| All Dimensions in mm |       |      |      |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 2.30          |
| C1         | 6.40          |
| X          | 1.20          |
| X1         | 3.30          |
| Y          | 1.60          |
| Y1         | 1.60          |
| Y2         | 8.00          |

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